## NSN 5961-01-299-4404

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-299-4404 **Inclosure Material:** Glass **Overall Length:** 0.097 inches **Terminal Length:** 0.064 inches **Overall Diameter:** 0.124 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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